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(to be used for	FORM	filing)	First Named Inventor Art Unit Examiner Name			Jaiprakash, et al. 2186 TBA
Total Number of	Pages in This Submission	# 1	Attorney Docket Number		14 4.2 . 14 4.4	112020.143US2 NAN-19
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Firm Nama	SIGNA	TURE C	F APPLICANT, ATTO	RNEY, O	R AG	ENT
Firm Name	Wilmer Cutler Picke	ring Hale	and Dorr LLP			
Signature	7	<u> </u>	SW			
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Jaiprakash et al.

Application No.:

10/776,059

Examiner: Unknown

Filed:

February 11, 2004

Group Art Unit: 2186

For:

Devices Having Horizontally-Disposed Nanofabric Articles and Methods

of Making the Same

Atty. Docket No.:

112020.143 US2 (NAN-19)

CERTIFICATE OF MAILING UNDER 37 CFR 1.8(a)

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Sir:

Applicants and their legal representatives hereby make of record on the attached Form PTO-1449 the following publications which are known to them and considered warranting disclosure under 37 C.F.R. §1.56 and 1.97-98.

Copies of the publications listed on the attached Form PTO-1449, with the exception of the cited U.S. Patents and the U.S. published applications, are submitted herewith. It is respectfully requested that the Examiner initial and return a copy of the subject Form PTO-1449 with the next Patent Office communication.

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Jaiprakash et al.

Page 2

The submission of these publications does not constitute a representation by the

Applicants that a search has been made or that no better art exists and does not constitute an

admission that the listed publications are material or constitute "prior art." Applicants reserve

the right to take appropriate action to establish the patentability of the disclosed invention over

the listed publications, should one or more of the publications be applied against the claims of

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It is Applicants' belief that the Information Disclosure Statement is being filed prior to

the mailing date of the first Office Action on the merits and, therefore, no fee is due. However,

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Respectfully submitted,

Dated: January 3, 2005

Peter M. Dichiara

Registration No. 38,005

Attorney for Applicants

Wilmer Cutler Pickering Hale and Dorr LLP

60 State Street

Boston, Massachusetts 02109

Tel: (617) 526-6466

Fax: (617) 526-5000

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0 6 200 TATEMENT BY APPLICANT (Use as many sheets as necessary)	First Named Inventor	Jaiprakash et al.	
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 Application Number
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 First Named Inventor
 Jaiprakash et al.

 Art Unit
 2186

 Examiner Name
 TBA

 Attorney Docket Number
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0 6 100 STATEMENT BY APPLICANT	First Named Inventor	Jaiprakash et al.	
(Use as many sheets as necessary)	Art Unit	2186	
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